Diode Semiconductor Device - Page 1 of 1



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1	Inclosure Material:
	Metal
(Overall Length:
	Between 0.195 inches and 0.350 inches
	Terminal Length:
	1.000 inches
(Overall Diameter:
I	Between 0.215 inches and 0.265 inches
I	Electrode Internally-electrically Connected To Case:
(Cathode
I	Mounting Method:
-	Terminal
I	Features Provided:
I	Hermetically sealed case
;	Semiconductor Material:
ę	Silicon
,	Voltage Rating In Volts Per Characteristic:
8	8.2 regulator voltage
1	Voltage Tolerance In Percent:
	-5.0/+5.0
(Current Rating Per Characteristic:
	31.00 milliamperes all primaries horsepower metric and 115.00 milliamperes repetitive peak forward current
I	Power Rating Per Characteristic:
	1.0 watts small-signal input power, common-collector preset
I	Maximum Operating Tempurature Per Measurement Point:
	175.0 degrees celsius ambient air
•	Test Data Document:
8	81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
1	format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
(environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
•	Terminal Type And Quantity:
2	2 uninsulated wire lead
;	Specification Data:
ł	81349-mil-s-19500/115 government specification
;	Shelf Life:
I	N/a
l	Unit Of Measure:
I	Demilitarization:
I	No
	Filg:
	A110a0
	Mil-std (military Standard):
I	Mil-prf-19500 spec.